Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.100 inches

# Terminal Length:

0.250 inches

#### **Overall Height:**

0.050 inches

### **Overall Width:**

0.070 inches

## **Mounting Method:**

Terminal

#### **Features Provided:**

Electrostatic sensitive

#### **Semiconductor Material:**

Silicon

## Voltage Rating In Volts Per Characteristic:

150.0 reverse breakdown voltage, instantaneous

### **Power Rating Per Characteristic:**

100.0 milliwatts small-signal input power, common-collector

## **Capacitance Rating In Picofarads:**

0.25

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

### **Terminal Type And Quantity:**

2 ribbon

Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

No

### Fiig:

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